

| $BV_{DSX}$<br>$BV_{DGX}$ | $R_{DS(on)}$<br>(max) | $I_{DSS}$ (min) | Package |
|--------------------------|-----------------------|-----------------|---------|
| 600V                     | 44Ω                   | 100mA           | SOT-223 |

### Features

- High Breakdown Voltage: 600V
- On-Resistance: 44Ω max. at 25°C
- Low  $V_{GS(off)}$  Voltage: -1.4 to -3.1V
- High Input Impedance
- Small Package Size: SOT-223

### Applications

- Current Regulator
- Normally-On Switches
- Solid State Relays
- Converters
- Telecommunications
- Power Supply

### Description

The CPC3960 is a 600V, N-channel, depletion-mode, Field Effect Transistor (FET) created using IXYS Integrated Circuits Division's proprietary vertical DMOS process. Yielding a robust device with high input impedance, this process enables world class, high voltage MOSFET performance with an economical silicon gate architecture.

As with all MOS devices, the FET structure prevents thermal runaway and thermal-induced secondary breakdown, which makes the CPC3960 ideal for use in high-power applications.

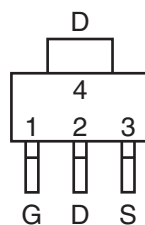
The CPC3960 is a highly reliable FET device that has been used extensively in IXYS Integrated Circuits Division's Solid State Relays for industrial and telecommunications applications.

The CPC3960 is available in the SOT-223 package.

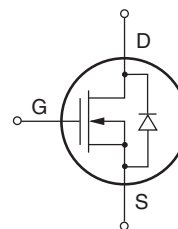
### Ordering Information

| Part #     | Description                        |
|------------|------------------------------------|
| CPC3960ZTR | SOT-223: Tape and Reel (1000/Reel) |

### Package Pinout



### Circuit Symbol



### Absolute Maximum Ratings @ 25°C

| Parameter                              | Ratings     | Units |
|--|-------------|-------|
| Drain-to-Source Voltage                | 600         | V     |
| Gate-to-Source Voltage                 | ±15         | V     |
| Pulsed Drain Current                   | 150         | mA    |
| Total Package Dissipation <sup>1</sup> | 1.8         | W     |
| Operational Temperature                | -55 to +125 | °C    |
| Junction Temperature, Maximum          | +125        | °C    |
| Storage Temperature                    | -55 to +125 | °C    |

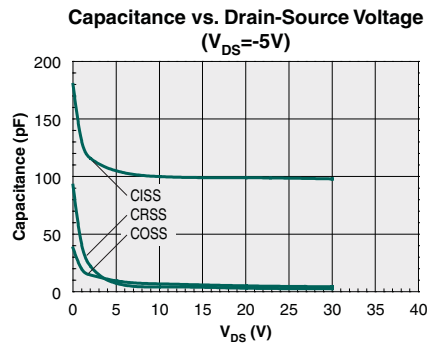
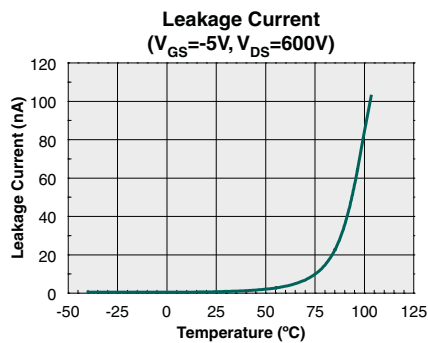
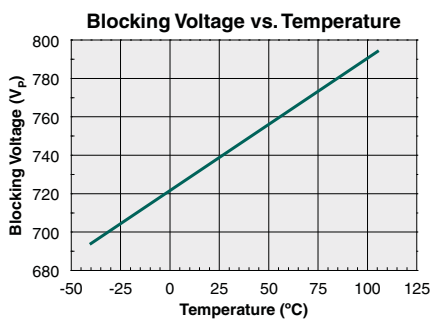
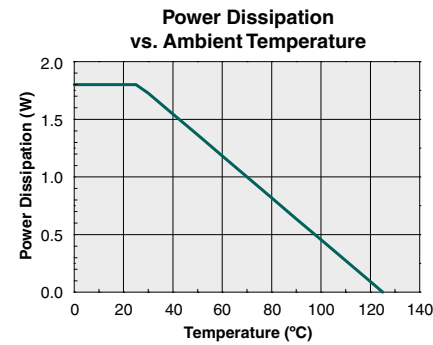
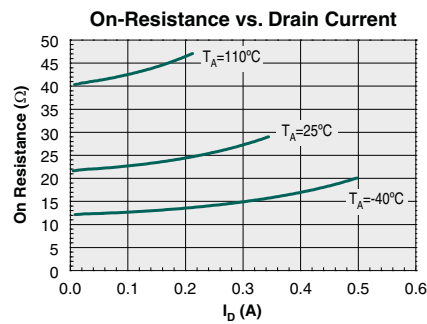
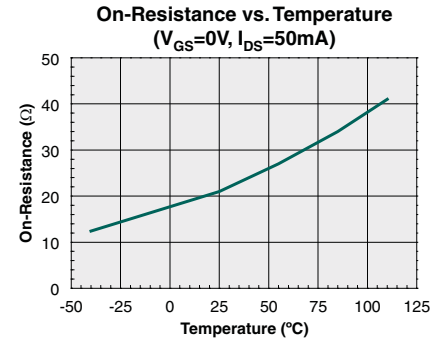
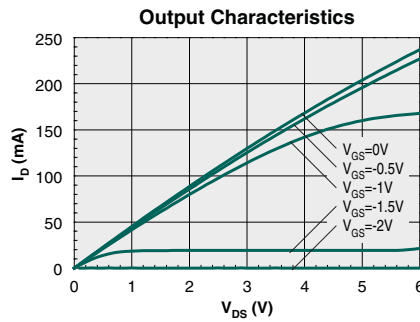
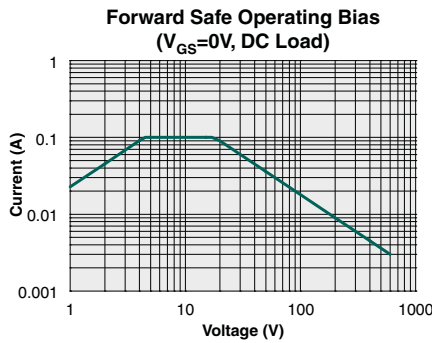
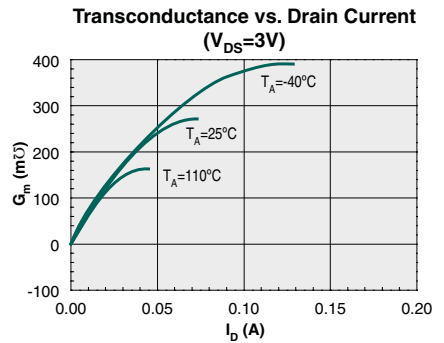
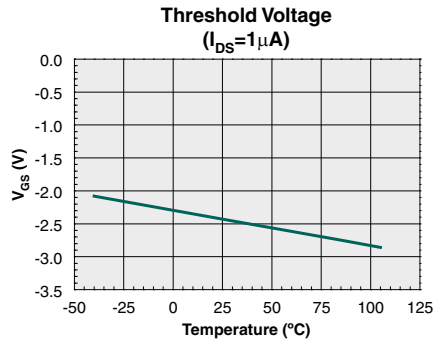
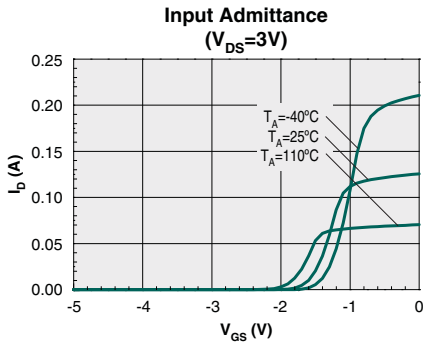
Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

<sup>1</sup> Mounted on 1"x1" 2 oz. Copper FR4 board.

### Electrical Characteristics @ 25°C (Unless Otherwise Noted)

| Parameter                                  | Symbol            | Conditions                                       | Min  | Typ  | Max  | Units |
|--|-------------------|--|------|------|------|-------|
| Drain-to-Source Breakdown Voltage          | $BV_{DSX}$        | $V_{GS} = -5.5V, I_D = 100\mu A$                 | 600  | -    | -    | V     |
| Gate-to-Source Off Voltage                 | $V_{GS(off)}$     | $V_{DS} = 15V, I_D = 1\mu A$                     | -1.4 | -    | -3.1 | V     |
| Change in $V_{GS(off)}$ with Temperature   | $dV_{GS(off)}/dT$ | $V_{DS} = 15V, I_D = 1\mu A$                     | -    | -    | 4.5  | mV/°C |
| Gate Body Leakage Current                  | $I_{GSS}$         | $V_{GS} = \pm 15V, V_{DS} = 0V$                  | -    | -    | 100  | nA    |
| Drain-to-Source Leakage Current            | $I_{D(off)}$      | $V_{GS} = -5.5V, V_{DS} = 600V$                  | -    | -    | 1    | μA    |
| Saturated Drain-to-Source Current          | $I_{DSS}$         | $V_{GS} = 0V, V_{DS} = 15V$                      | 100  | -    | -    | mA    |
| Static Drain-to-Source On-State Resistance | $R_{DS(on)}$      | $V_{GS} = 0V, I_D = 100mA, V_{DS} = 10V$         | -    | -    | 44   | Ω     |
| Change in $R_{DS(on)}$ with Temperature    | $dR_{DS(on)}/dT$  |  | -    | -    | 2.5  | %/°C  |
| Forward Transconductance                   | $G_{fs}$          | $I_D = 50mA, V_{DS} = 10V$                       | 100  | -    | -    | mS    |
| Input Capacitance                          | $C_{ISS}$         | $V_{GS} = -3.5V$<br>$V_{DS} = 25V$<br>$f = 1MHz$ | -    | 100  | -    | pF    |
| Common Source Output Capacitance           | $C_{OSS}$         |  | -    | 6.8  | -    |       |
| Reverse Transfer Capacitance               | $C_{RSS}$         |  | -    | 4.2  | -    |       |
| Source-Drain Diode Voltage Drop            | $V_{SD}$          | $V_{GS} = -5V, I_{SD} = 150mA$                   | -    | 0.72 | 1    | V     |
| Thermal Resistance                         |                   |  |      |      |      |       |
| Junction to Ambient                        | $\Theta_{JA}$     | -  | -    | 55   | -    | °C/W  |
| Junction to Case                           | $\Theta_{JC}$     | -  | -    | 23   | -    |       |

**PERFORMANCE DATA @ 25°C (Unless Otherwise Noted)\***



\*The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

## Manufacturing Information

### Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

| Device   | Moisture Sensitivity Level (MSL) Rating |
|----------|---|
| CPC3960Z | MSL 1                                   |

### ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

### Reflow Profile

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

| Device   | Maximum Temperature x Time |
|----------|----------------------------|
| CPC3960Z | 260°C for 30 seconds       |

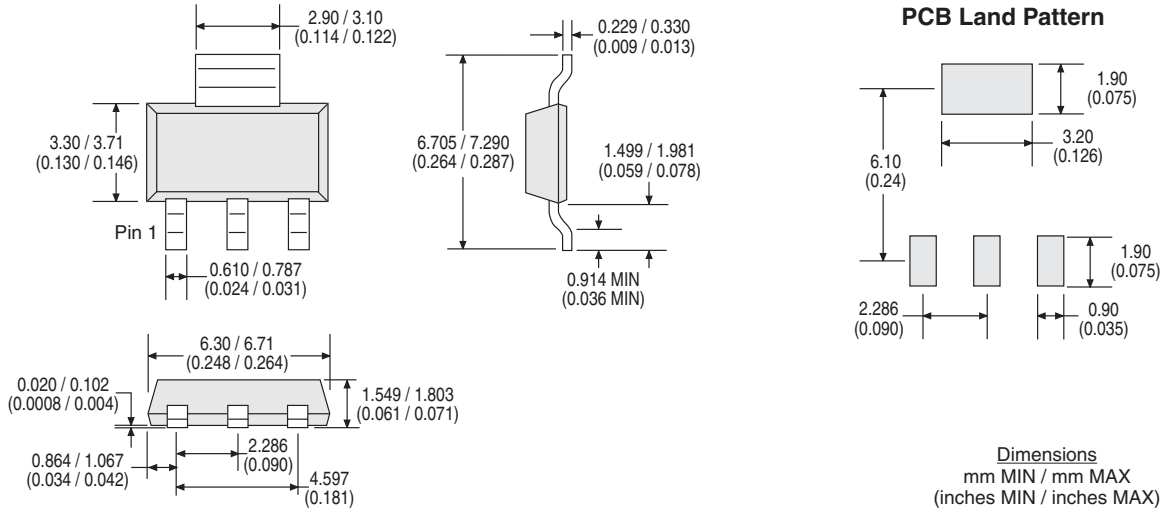
### Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable, and the use of a short drying bake may be necessary. Chlorine-based or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.

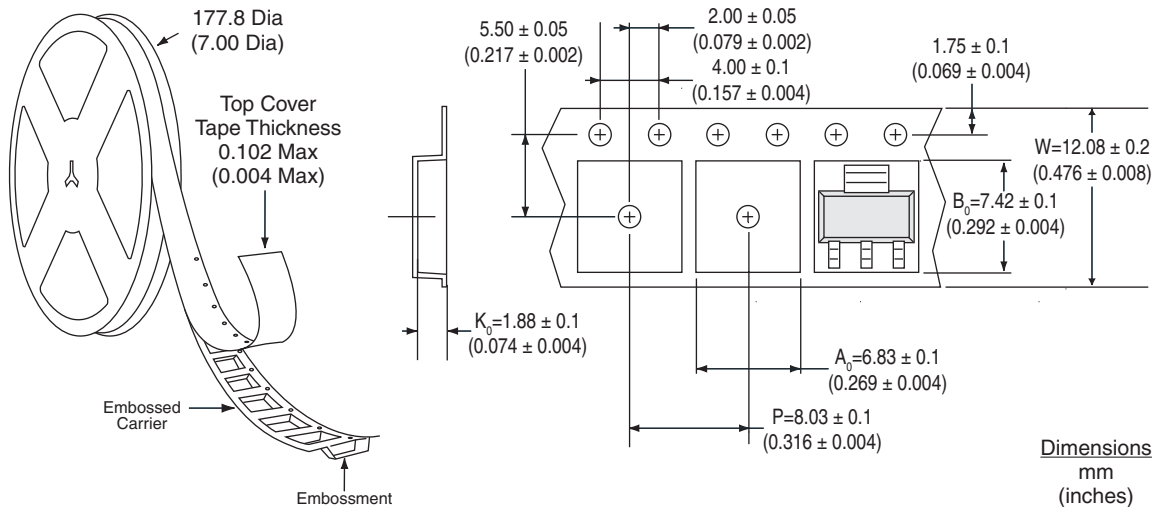


**Mechanical Dimensions**

**CPC3960Z**



**CPC3960ZTR Tape & Reel**



For additional information please visit our website at: [www.ixysic.com](http://www.ixysic.com)

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